# N-Channel Logic Level PowerTrench<sup>®</sup> MOSFET

# 40 V, 300 A, 0.55 m $\Omega$

# Features

- Typical  $R_{DS(on)} = 0.47 \text{ m}\Omega$  at  $V_{GS} = 10 \text{ V}$ ,  $I_D = 80 \text{ A}$
- Typical  $Q_{g(tot)} = 269 \text{ nC}$  at  $V_{GS} = 10 \text{ V}$ ,  $I_D = 80 \text{ A}$
- UIS Capability
- Qualified to AEC Q101
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

## Applications

- Automotive Engine Control
- PowerTrain Management
- Solenoid and Motor Drivers
- Integrated Starter/Alternator
- Primary Switch for 12 V Systems

# **MAXIMUM RATINGS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Symbol	Parameter	Value	Unit
V <sub>DSS</sub>	Drain-to-Source Voltage	40	V
V <sub>GS</sub>	Gate-to-Source Voltage	±20	V
I <sub>D</sub>			A
	Pulsed Drain Current, $T_C = 25^{\circ}C$	(See Figure 4)	А
E <sub>AS</sub>	Single Pulse Avalanche Energy (Note 2)	913	mJ
PD	Power Dissipation	429	W
	Derate Above 25°C	2.86	W/∘C
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature	–55 to +175	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Current is limited by bondwire configuration.

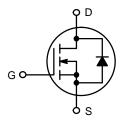
2. Starting  $T_J = 25^{\circ}$ C,  $L = 530 \mu$ H,  $I_{AS} = 64$  A,  $V_{DD} = 40$  V during inductor charging and  $V_{DD} = 0$  V during time in avalanche.



# **ON Semiconductor®**

## www.onsemi.com

V <sub>DSS</sub>	R <sub>DS(ON)</sub> MAX	I <sub>D</sub> MAX	
40 V	0.55 mΩ @ 10 V	300 A	

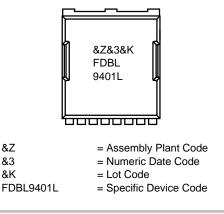


N-CHANNEL MOSFET



CASE 100CU

## MARKING DIAGRAM



## **ORDERING INFORMATION**

See detailed ordering and shipping information on page 7 of this data sheet.

## THERMAL CHARACTERISTICS

Symbol	Parameter	Value	Unit
$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction to Case	0.35	°C/W
$R_{\thetaJA}$	Thermal Resistance, Junction to Ambient (Note 3)	43	

 R<sub>θJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. R<sub>θJC</sub> is guaranteed by design, while R<sub>θJA</sub> is determined by the board design. The maximum rating presented here is based on mounting on a 1 in<sup>2</sup> pad of 2 oz copper.

# **ELECTRICAL CHARACTERISTICS** (T<sub>J</sub> = $25^{\circ}$ C unless otherwise noted)

Symbol	Parameter	Test Condition	Min	Тур	Max	Unit
OFF CHAR	ACTERISTICS	-	•			
BV <sub>DSS</sub>	Drain-to-Source Breakdown Voltage	$I_D = 250 \ \mu A, \ V_{GS} = 0 \ V$	40	-	-	V
I <sub>DSS</sub>	Drain-to-Source Leakage Current	$V_{DS} = 40 V, V_{GS} = 0 V$ $T_J = 25^{\circ}C$ $T_J = 175^{\circ}C$ (Note 4)			1 2000	μΑ
I <sub>GSS</sub>	Gate-to-Source Leakage Current	$V_{GS} = \pm 20 V$	-	-	±100	nA
ON CHARA	CTERISTICS	-	•			
V <sub>GS(th)</sub>	Gate-to-Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \ \mu A$	1	1.7	3	V
R <sub>DS(on)</sub>	Drain-to-Source On Resistance	$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 80 \text{ A}$	-	0.59	0.76	mΩ
		$V_{GS} = 10 \text{ V}, I_D = 80 \text{ A}$ $T_J = 25^{\circ}\text{C}$ $T_J = 175^{\circ}\text{C} \text{ (Note 4)}$		0.47 0.81	0.55 0.97	mΩ
DYNAMIC C	HARACTERISTICS			-	-	-
C <sub>iss</sub>	Input Capacitance	$V_{DS}$ = 20 V, $V_{GS}$ = 0 V, f = 1 MHz	-	19550	-	pF
Coss	Output Capacitance		-	5630	-	pF
C <sub>rss</sub>	Reverse Transfer Capacitance		-	509	-	pF
Rg	Gate Resistance	V <sub>GS</sub> = 0.5 V, f = 1 MHz	-	2.8	-	Ω
Q <sub>g(tot)</sub>	Total Gate Charge at 10 V	$V_{GS}$ = 0 V to 10 V, $V_{DD}$ = 32 V, $I_{D}$ = 80 A	-	269	376	nC
Q <sub>g(th)</sub>	Threshold Gate Charge	$V_{GS}$ = 0 V to 1 V, $V_{DD}$ = 32 V, $I_D$ = 80 A	-	17	-	nC
Q <sub>gs</sub>	Gate-to-Source Gate Charge	V <sub>DD</sub> = 32 V, I <sub>D</sub> = 80 A	-	56	-	nC
Q <sub>gd</sub>	Gate-to-Drain "Miller" Charge	V <sub>DD</sub> = 32 V, I <sub>D</sub> = 80 A	-	33	-	nC

### SWITCHING CHARACTERISTICS

t <sub>on</sub>	Turn-On Time	$V_{DD} = 20 \text{ V}, \text{ I}_{D} = 80 \text{ A}, \text{ V}_{GS} = 10 \text{ V},$	-	-	150	ns
t <sub>d(on)</sub>	Turn-On Delay Time	$R_{GEN} = 6 \Omega$	_	27	-	ns
t <sub>r</sub>	Turn-On Rise Time		_	49	-	ns
t <sub>d(off)</sub>	Turn-Off Delay Time		-	196	-	ns
t <sub>f</sub>	Turn-Off Fall Time		-	79	-	ns
t <sub>off</sub>	Turn-Off Time		-	-	412	ns

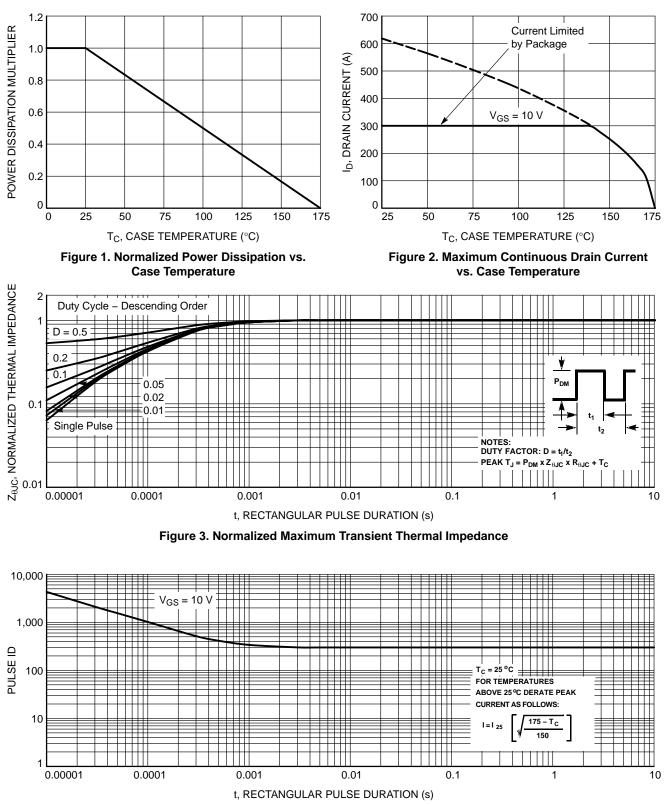
#### DRAIN-SOURCE DIODE CHARACTERISTICS

V <sub>SD</sub>	Source-to-Drain Diode Voltage	I <sub>SD</sub> = 80 A, V <sub>GS</sub> = 0 V	-	0.78	1.25	V
		$I_{SD} = 40 \text{ A}, V_{GS} = 0 \text{ V}$	-	0.74	1	
t <sub>rr</sub>	Reverse–Recovery Time	$I_F = 80 \text{ A}, \text{ d}I_{SD}/\text{d}t = 100 \text{ A}/\mu\text{s}$	-	130	195	ns
Q <sub>rr</sub>	Reverse–Recovery Charge		-	270	405	nC

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

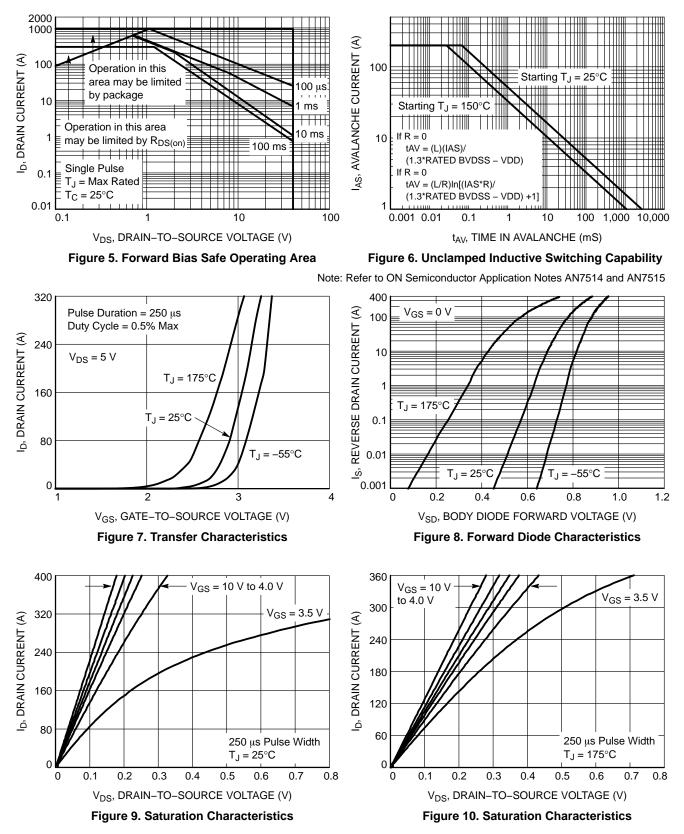
4. The maximum value is specified by design at  $T_J = 175^{\circ}$ C. Product is not tested to this condition in production.

# **TYPICAL CHARACTERISTICS**

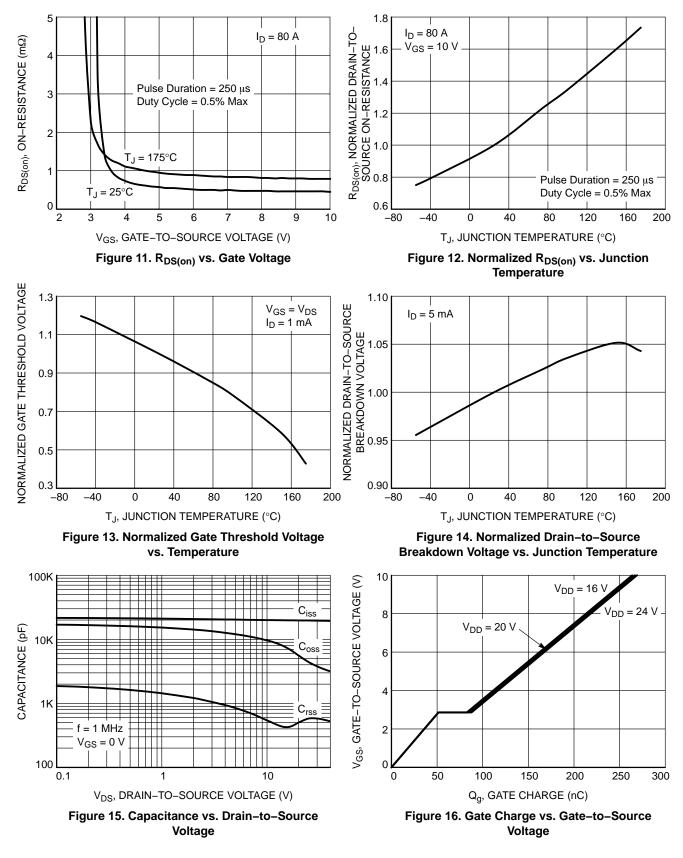




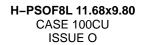
# **TYPICAL CHARACTERISTICS**

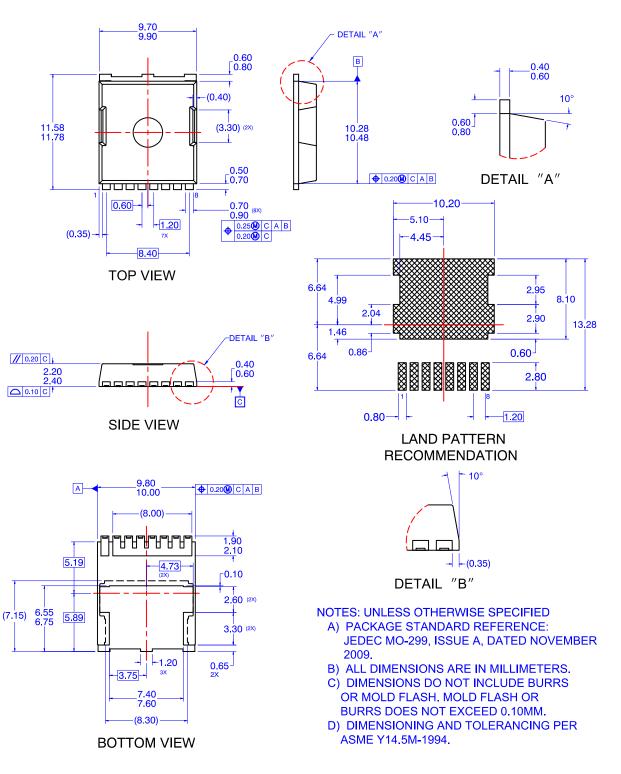


# **TYPICAL CHARACTERISTICS**



# PACKAGE DIMENSIONS





### PACKAGE MARKING AND ORDERING INFORMATION

Device	Marking	Package	Reel Size	Tape Width	Quantity
FDBL9401L-F085	FDBL9401L	H–PSOF8L (Pb-Free / Halogen Free)	13″	24 mm	2000 Units

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